NSN 5961-01-227-1946

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-227-1946 **Inclosure Material:** Metal **Overall Length:** 1.250 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter and 50.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**